

Linear Systems replaces discontinued Siliconix J210

The J210 is a n-channel JFET General Purpose amplifier with low noise and low leakage.

The TO-92 package is well suited for cost sensitive applications and mass production.

(See Packaging Information).

J210 Benefits:

- High gain
- Low Leakage
- Low Noise

J210 Applications:

- General Purpose Amplifiers
- UHF / VHF Amplifiers
- Mixers
- Oscillators

FEATURES

DIRECT REPLACEMENT FOR SILICONIX J210

HIGH GAIN	$g_{fs} = 7000 \mu mho$ MIN
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HIGH INPUT IMPEDANCE	$I_{GSS} = 100 pA$ max
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LOW INPUT CAPACITANCE	$C_{iss} = 5 pF$
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ABSOLUTE MAXIMUM RATINGS @ 25°C (unless otherwise noted)

Maximum Temperatures

Storage Temperature	-55°C to +150°C
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Operating Junction Temperature	-55°C to +135°C
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Maximum Power Dissipation

Continuous Power Dissipation	360mW
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Derating over temperature	3.27 mW/°C
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MAXIMUM CURRENT

Gate Current (Note 1)	10mA
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MAXIMUM VOLTAGES

Gate to Drain Voltage or Gate to Source Voltage	-25V
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J210 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
BV_{GSS}	Gate to Source Breakdown Voltage	-25	--	--	V	$V_{DS} = 0V, I_G = -1 \mu A$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	-1	--	-3	V	$V_{DS} = 15V, I_D = 1nA$
I_{DSS}	Drain to Source Saturation Current (Note 2)	2	--	15	mA	$V_{DS} = 15V, V_{GS} = 0V$
I_{GSS}	Gate Reverse Current (Note 3)	--	--	-100	pA	$V_{DS} = 0V, V_{GS} = -15V$
I_G	Gate Operating Current (Note 3)	--	-10	--	pA	$V_{DS} = 10V, I_D = 1mA$
$r_{DS(on)}$	Drain to Source On Resistance	--	--	50	Ω	$I_G = 1mA, V_{DS} = 0V$

J210 DYNAMIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
g_{fs}	Forward Transconductance	4000	--	12000	μmho	$V_{DS} = 15V, V_{GS} = 0V, f = 1kHz$
g_{os}	Output Conductance	--	--	150	μmho	$V_{DS} = 15V, V_{GS} = 0V, f = 1kHz$
C_{iss}	Input Capacitance	--	4	--	pF	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$
C_{rss}	Reverse Transfer Capacitance	--	1	--	pF	$V_{DS} = 15V, V_{GS} = 0V, f = 1kHz$
e_n	Equivalent Noise Voltage	--	10	--	nV/VHz	$V_{DS} = 15V, V_{GS} = 0V, f = 1kHz$

J210 SWITCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	UNITS	CONDITIONS
$t_{d(on)}$	Turn On Time	2	$V_{DD} = 10V$ $V_{GS(H)} = 0V$
t_r	Turn On Rise Time	2	See Switching Circuit
$t_{d(off)}$	Turn Off Time	6	
t_f	Turn Off Fall Time	15	

Note 1 - Absolute maximum ratings are limiting values above which J210 serviceability may be impaired.

Note 2 - Pulse test duration = 2ms

Note 3 - Approximately doubles for every 10°C increase in T_A

Micross Components Europe

Available Packages:

TO-92 (Bottom View)



Tel: +44 1603 788967

Email: chipcomponents@micross.com

Web: <http://www.micross.com/distribution>

J210 in TO-92
J210 in bare die.

Please contact Micross for full package and die dimensions

